

DATA SHEET

74ABT16244A
74ABTH16244A
16-bit buffer/line driver (3-State)

Product specification
Supersedes data of 1998 Feb 25
IC23 Data Handbook

1998 Oct 07

16-bit buffer/line driver (3-State)

74ABT16244A
74ABTH16244A

FEATURES

- 16-bit bus interface
- Multiple V_{CC} and GND pins minimize switching noise
- Power-up 3-State
- 3-State buffers
- Output capability: +64 mA/-32mA
- Live insertion/extraction permitted
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- 74ABTH16244A incorporates bus hold data inputs which eliminate the need for external pull up resistors to hold unused inputs
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs

DESCRIPTION

The 74ABT16244A high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16244A device is a 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables ($1\overline{OE}$, $2\overline{OE}$, $3\overline{OE}$, $4\overline{OE}$), each controlling four of the 3-State outputs.

Two options are available, 74ABT16244A which does not have the bus hold feature and 74ABTH16244A which incorporates the bus hold feature.

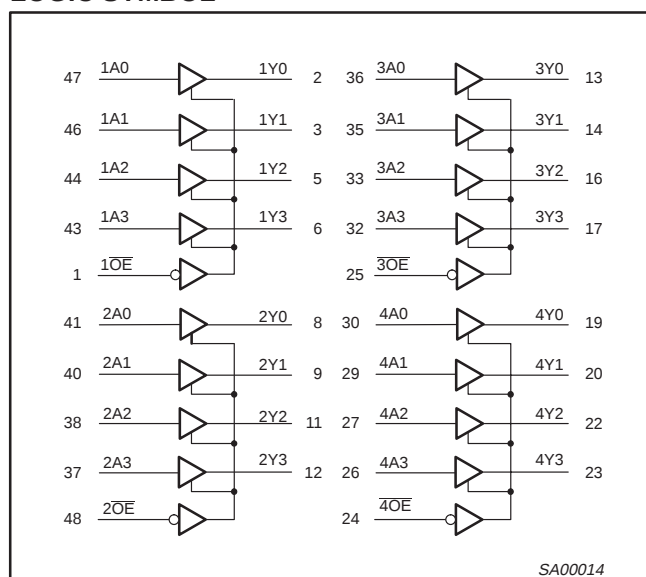
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}$; GND = 0V	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay nAx to nYx	$C_L = 50\text{pF}$; $V_{CC} = 5\text{V}$	1.7 2.1	ns
C_{IN}	Input capacitance	$V_I = 0\text{V}$ or V_{CC}	4	pF
C_{OUT}	Output capacitance	$V_O = 0\text{V}$ or V_{CC} ; 3-State	7	pF
I_{CCZ}	Quiescent supply current	Outputs disabled; $V_{CC} = 5.5\text{V}$	450	μA
I_{CCL}		Outputs low; $V_{CC} = 5.5\text{V}$	10	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to $+85^{\circ}\text{C}$	74ABT16244A DL	BT16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to $+85^{\circ}\text{C}$	74ABT16244A DGG	BT16244A DGG	SOT362-1
48-Pin Plastic SSOP Type III	-40°C to $+85^{\circ}\text{C}$	74ABH16244A DL	BH16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to $+85^{\circ}\text{C}$	74ABH16244A DGG	BH16244A DGG	SOT362-1

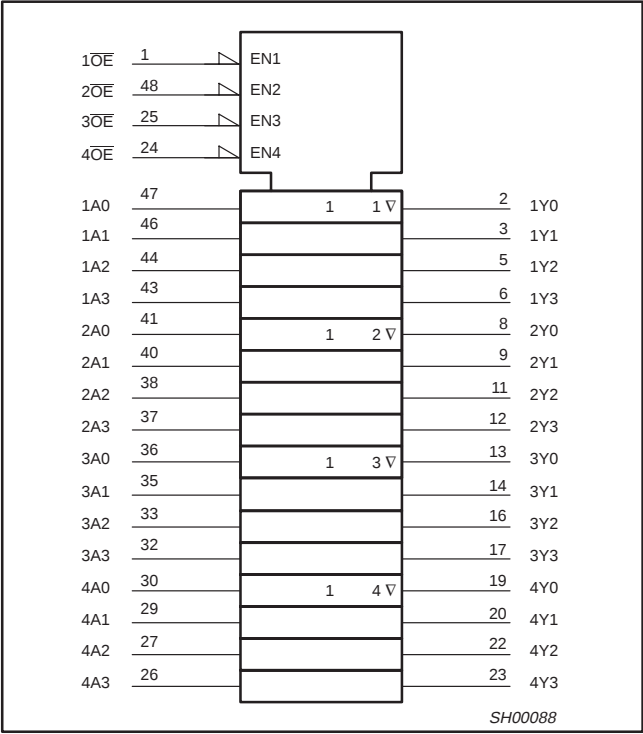
LOGIC SYMBOL



16-bit buffer/line driver (3-State)

74ABT16244A
74ABTH16244A

LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

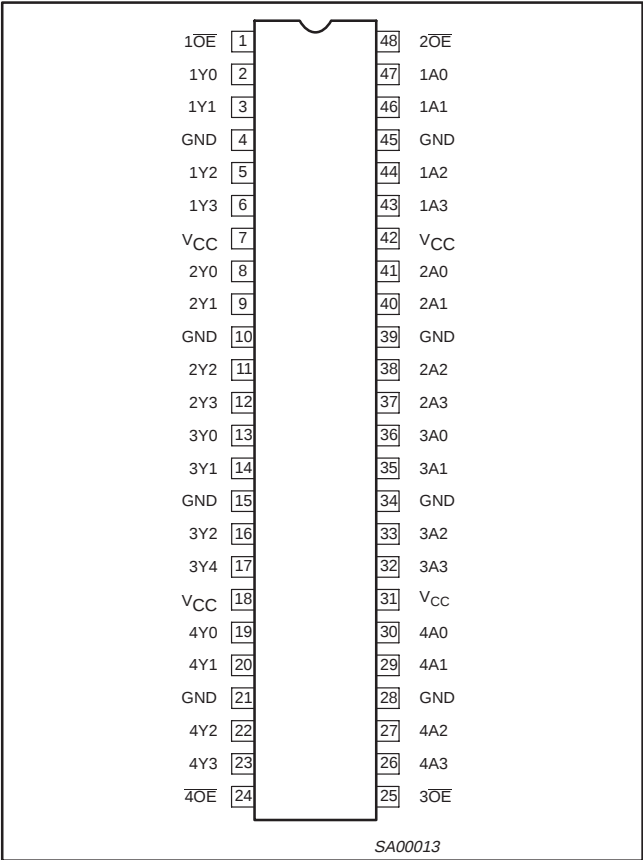
PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 – 1A3, 2A0 – 2A3, 3A0 – 3A3, 4A0 – 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 – 1Y3, 2Y0 – 2Y3, 3Y0 – 3Y3, 4Y0 – 4Y3	Data outputs
1, 48 25, 24	1OE, 2OE, 3OE, 4OE	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	VCC	Positive supply voltage

FUNCTION TABLE

INPUTS		OUTPUTS
nOE	nAx	nYx
L	L	L
L	H	H
H	X	Z

H = High voltage level
L = Low voltage level
X = Don't care
Z = High impedance "off" state

PIN CONFIGURATION



16-bit buffer/line driver (3-State)

74ABT16244A
74ABTH16244AABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		−0.5 to +7.0	V
I_{IK}	DC input diode current	$V_I < 0$	−18	mA
V_I	DC input voltage ³		−1.2 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	−50	mA
V_{OUT}	DC output voltage ³	output in Off or High state	−0.5 to +5.5	V
I_{OUT}	DC output current	output in Low state	128	mA
		output in High state	−64	
T_{stg}	Storage temperature range		−65 to 150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	4.5	5.5	V
V_I	Input voltage	0	V_{CC}	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level input voltage		0.8	V
I_{OH}	High-level output current		−32	mA
I_{OL}	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
T_{amb}	Operating free-air temperature range	−40	+85	°C

16-bit buffer/line driver (3-State)

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DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS					UNIT
				T _{amb} = +25°C			T _{amb} = -40°C to +85°C		
				Min	Typ	Max	Min	Max	
V _{IK}	Input clamp voltage	V _{CC} = 4.5V; I _{IK} = -18mA			-0.9	-1.2		-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 4.5V; I _{OH} = -3mA; V _I = V _{IL} or V _{IH}		2.5	2.9		2.5		V
		V _{CC} = 5.0V; I _{OH} = -3mA; V _I = V _{IL} or V _{IH}		3.0	3.4		3.0		
		V _{CC} = 4.5V; I _{OH} = -32mA; V _I = V _{IL} or V _{IH}		2.0	2.4		2.0		
V _{OL}	Low-level output voltage	V _{CC} = 4.5V; I _{OL} = 64mA; V _I = V _{IL} or V _{IH}			0.42	0.55		0.55	V
I _I	Input leakage current	V _{CC} = 5.5V; V _I = GND or 5.5V			±0.01	±1.0		±1.0	µA
I _I	Input leakage current 74ABTH16244A	V _{CC} = 5.5V; V _I = V _{CC} or GND	Control pins		±0.01	±1		±1	µA
		V _{CC} = 5.5V; V _I = V _{CC}	Data Pins		0.01	1		1	
		V _{CC} = 5.5V; V _I = 0			-2	-3		-5	
I _{HOLD}	Bus Hold current A inputs ⁴ 74ABTH16244A	V _{CC} = 4.5V; V _I = 0.8V		50			50		µA
		V _{CC} = 4.5V; V _I = 2.0V		-75			-75		
		V _{CC} = 5.5V; V _I = 0 to 5.5V		±500					
I _{OFF}	Power-off leakage current	V _{CC} = 0.0V; V _O or V _I ≤ 4.5V			±5.0	±100		±100	µA
I _{PU} /I _{PD}	Power-up/down 3-State output current	V _{CC} = 2.0V; V _O = 0.5V; V _I = GND or V _{CC} ; V _{OE} = V _{CC}			±5.0	±50		±50	µA
I _{OZH}	3-State output High current	V _{CC} = 5.5V; V _O = 5.5V; V _I = V _{IL} or V _{IH}			0.1	10		10	µA
I _{OZL}	3-State output Low current	V _{CC} = 5.5V; V _O = 0.0V; V _I = V _{IL} or V _{IH}			-0.1	-10		-10	µA
I _{CEX}	Output High leakage current	V _{CC} = 5.5V; V _O = 5.5V; V _I = GND or V _{CC}			5.0	50		50	µA
I _O	Output current ¹	V _{CC} = 5.5V; V _O = 2.5V		-50	-100	-180	-50	-180	mA
I _{CCH}	Quiescent supply current ³	V _{CC} = 5.5V; Outputs High, V _I = GND or V _{CC}			0.45	1.0		1.0	mA
I _{CCL}		V _{CC} = 5.5V; Outputs Low, V _I = GND or V _{CC}			10	19		19	mA
I _{CCZ}		V _{CC} = 5.5V; Outputs 3-State; V _I = GND or V _{CC}			0.45	1.0		1.0	µA
ΔI _{CC}	Additional supply current per input pin ^{2, 3}	Outputs enabled, one data input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V			100	250		250	µA
		Outputs disabled, one data input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V			100	250		250	
		Control pins, outputs disabled, one enable input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V			100	250		250	

NOTES:

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
2. This is the increase in supply current for each input at 3.4V.
3. This data sheet limit may vary among suppliers.
4. This is the bus hold overdrive current required to force the input to the opposite logic state.

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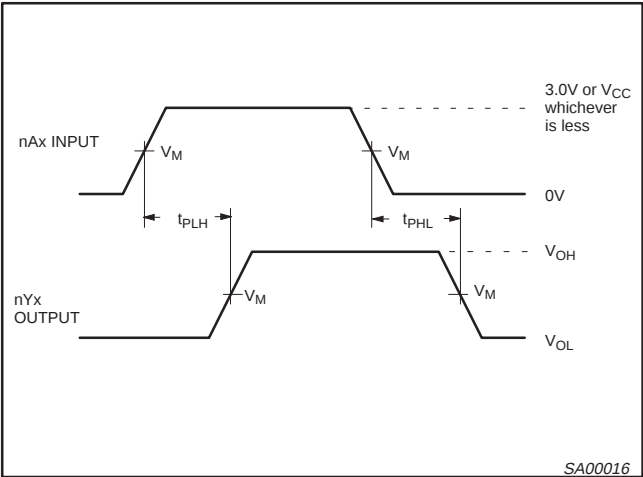
AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5\text{ns}$; $C_L = 50\text{pF}$, $R_L = 500\Omega$

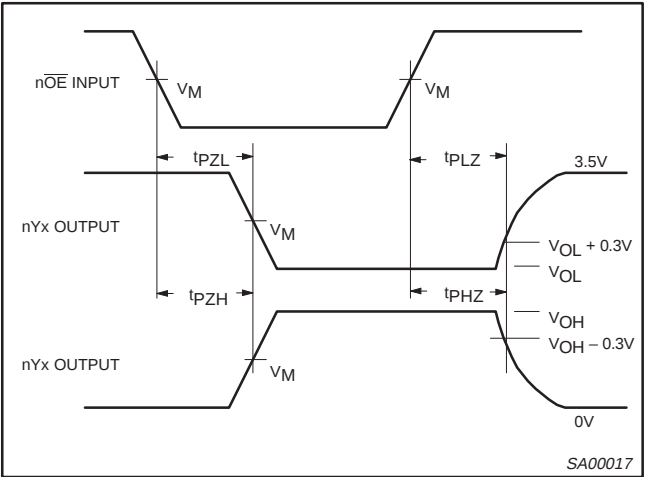
SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			T _{amb} = +25°C V _{CC} = +5.0V			T _{amb} = -40°C to +85°C V _{CC} = +5.0V ±0.5V		
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1.1 1.3	1.7 2.1	2.6 2.9	1.1 1.3	2.8 3.4	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.6 2.3	2.7 3.5	3.7 4.0	1.6 2.3	4.5 4.8	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	2.0 1.6	3.0 2.4	4.0 3.2	2.0 1.6	4.6 4.1	ns

AC WAVEFORMS

$V_M = 1.5\text{V}$, $V_{\text{IN}} = \text{GND to } 3.0\text{V}$



Waveform 1. Input (An) to Output (Yn) Propagation Delays

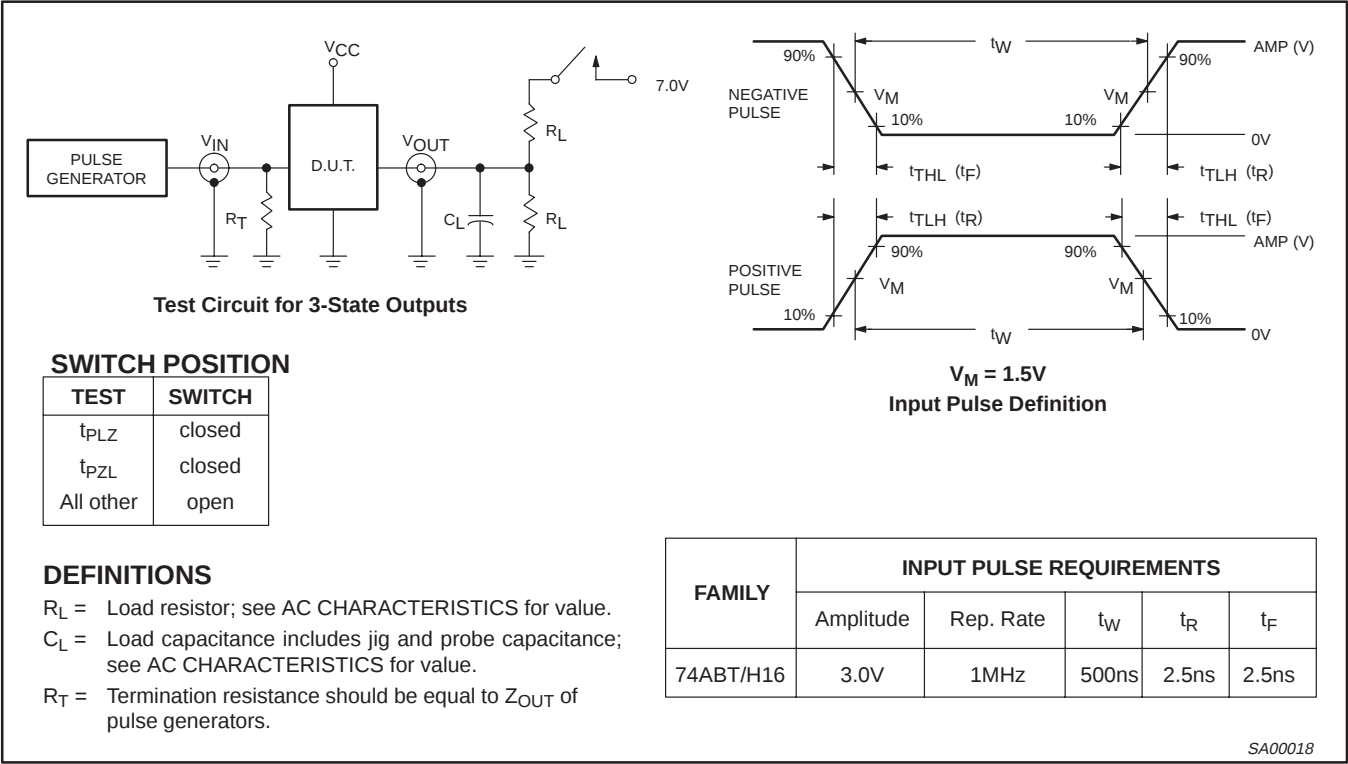


Waveform 2. 3-State Output Enable and Disable Times

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TEST CIRCUIT AND WAVEFORMS

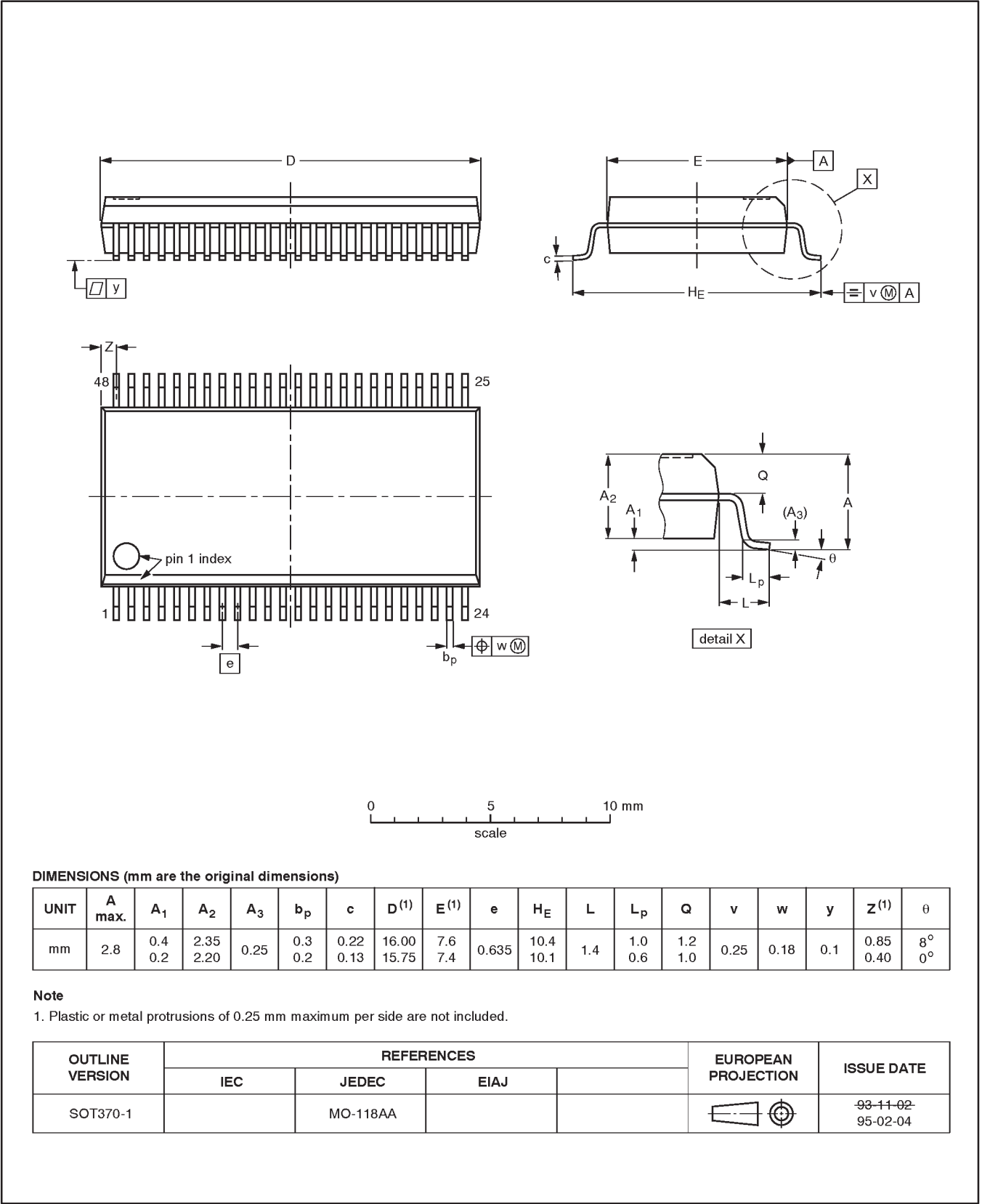


16-bit buffer/line driver (3-State)

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SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1

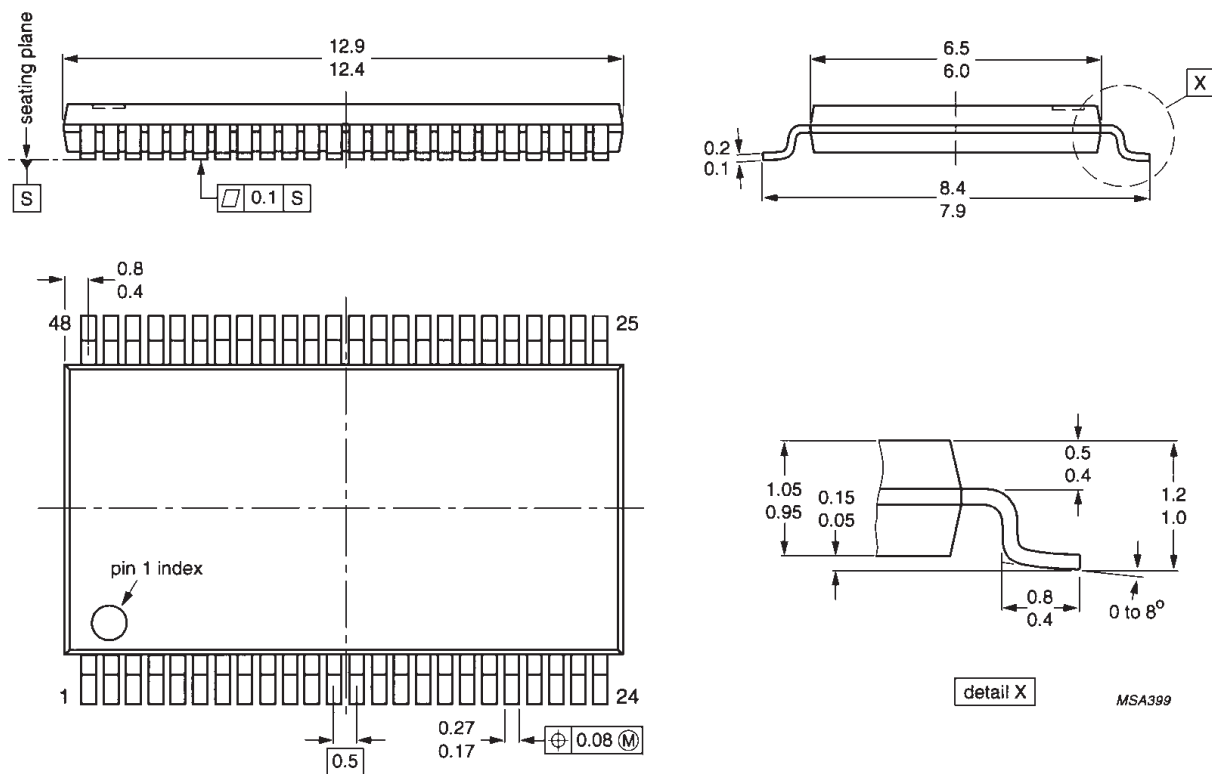


16-bit buffer/line driver (3-State)

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74ABTH16244A

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



16-bit buffer/line driver (3-State)

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74ABTH16244A

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Philips Semiconductors
811 East Arques Avenue
P.O. Box 3409
Sunnyvale, California 94088-3409
Telephone 800-234-7381

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